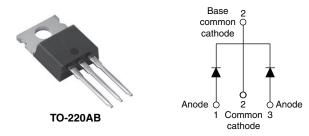


www.vishay.com

Vishay Semiconductors





PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 10 A			
V _R	150 V			
V _F at I _F	0.66 V			
I _{RM} max.	5 mA at 125 °C			
TJ	175 °C			
Diode variation	Common cathode			
E _{AS}	2.45 mJ			

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation



COMPLIANT

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength RoHS and moisture resistance
- HALOGEN • Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and gualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	20	A		
V _{RRM}		150	V		
I _{FSM}	t _p = 5 μs sine	1030	А		
V _F	10 A_{pk} , $T_J = 125 \ ^{\circ}C$ (per leg)	0.66	V		
TJ	Range	- 55 to 175	C°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20CTQ150PbF	VS-20CTQ150-N3	UNITS	
Maximum DC reverse voltage	V _R	150	150	V	
Maximum working peak reverse voltage	V _{RWM}	150	150	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS					
Maximum average per leg		50 % duty cycle at T_{C} = 154 °C, rectangular waveform		10	А	
See fig. 5 per device	I _{F(AV)}			20		
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	1030		
non-repetitive surge current per leg I _{FSM} See fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	180	A	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.7 A, L = 10 mH		2.45	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.7	А	

Revision: 26-Aug-11

Document Number: 94164

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors

- 6	
- 1	
	FIFLIKKAI SPELIEKAIKINS
- 1	ELECTRICAL SPECIFICATIONS

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS	
Maximum forward voltage drop per leg See fig. 1		10 A	T.I = 25 °C	0.80	0.88	V	
	V (1)	20 A	$1_{\rm J} = 25$ C	0.90	1.0		
	V _{FM} ⁽¹⁾	10 A	T 405 00	0.63	0.66		
		20 A	T _J = 125 °C	0.73	0.77		
Maximum reverse leakage current per leg		T _J = 25 °C			25	μA	
See fig. 2	IRM	T _J = 125 °C	V _R = Rated V _R	2.7	5.0	mA	
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	280	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		-	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs	

Note

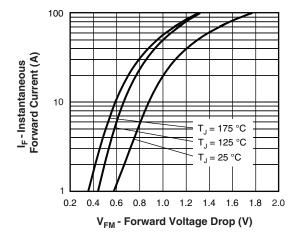
 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

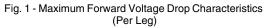
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C			
Maximum thermal resistance, junction to case per leg	Б	DC operation	2.0	°C/W			
Maximum thermal resistance, junction to case per package	– R _{thJC}	De operation	1.0				
Typical thermal resistance, case to heatsink	R _{thCS}	R _{thCS} Mounting surface, smooth and greased (Only for TO-220)					
Approvimate weight			2	g			
Approximate weight			0.07	oz.			
Mounting torque	1		6 (5)	kgf ⋅ cm			
Mounting torque maximum			12 (10)	(lbf · in)			
Marking device		Case style TO-220AB	20CT	Q150			

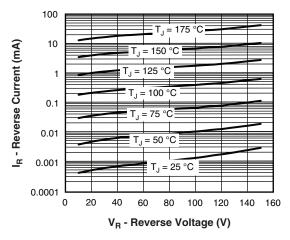


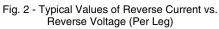
VS-20CTQ150PbF, VS-20CTQ150-N3

Vishay Semiconductors









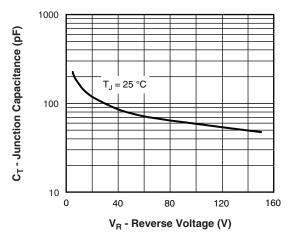
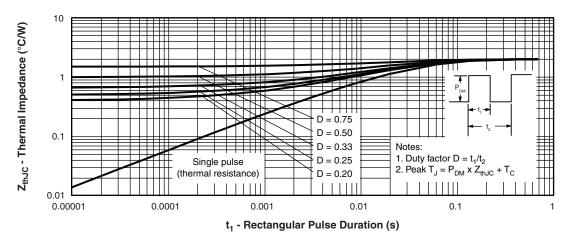
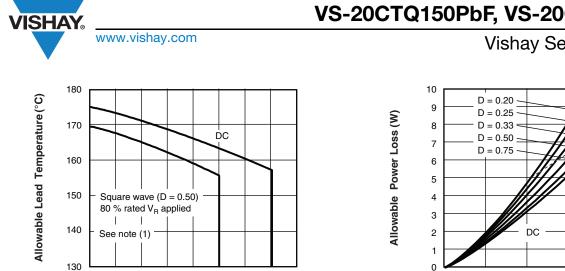


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





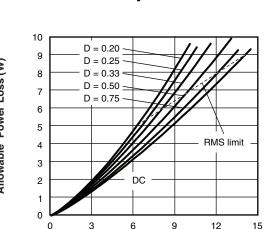
Revision: 26-Aug-11 3 Document Number: 94164 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000





I_{F(AV)} - Average Forward Current (A)

0 2 4 6 8 10 12 14 16



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

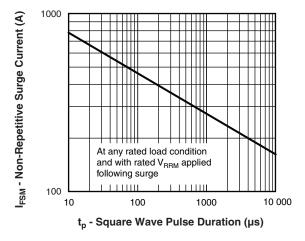


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

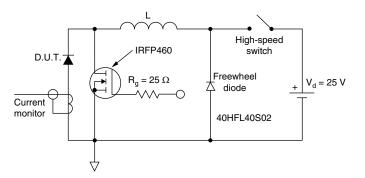


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

Revision: 26-Aug-11

4

Document Number: 94164

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-20CTQ150PbF, VS-20CTQ150-N3

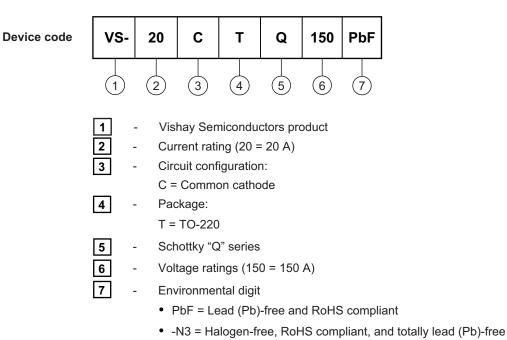
Vishay Semiconductors

VS-20CTQ150PbF, VS-20CTQ150-N3



Vishay Semiconductors

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-20CTQ150PbF	50	1000	Antistatic plastic tube		
VS-20CTQ150-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	INCHES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.